

### INCHANGE SEMICONDUCTOR

## isc N-Channel MOSFET Transistor

# IXFP20N85X

### • FEATURES

- With TO-220 packaging
- High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

#### APPLICATIONS

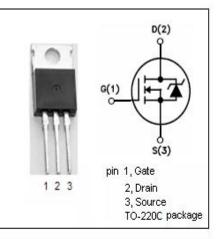
- Power supply
- Switching applications

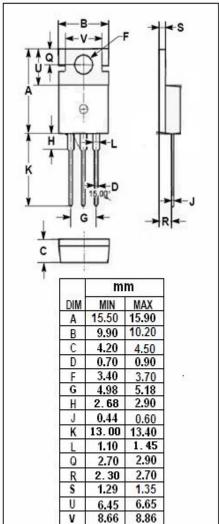
SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	850	v	
$V_{\text{GSS}}$	Gate-Source Voltage	±30	v	
ID	Drain Current-Continuous	20	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	50	А	
PD	Total Dissipation	540	W	
Tj	Operating Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	°C	

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.5	°C/W	
Rth(ch-a)	ch-a) Channel-to-ambient thermal resistance		°C <b>/W</b>	

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#### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1.0mA	850			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =2.5mA	3.5		5.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =10A			330	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±30V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 850V; V <sub>GS</sub> = 0V;Tj=25℃			25	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =20A, V <sub>GS</sub> = 0 V			1.4	V

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